

Technical Note

Power Supply IC Series for TFT-LCD Panels 5V Input Multi-channel System Power Supply IC



BD8153EFV

No.09035JBT09

Description

The BD8153EFV is a system power supply IC for TFT panels.A 1-chip IC providing a total of four voltages required for TFT panels, i.e., logic voltage, sauce voltage, gate high-level, and gate low-level voltage, thus constructing a TFT panel power supply with minimal components required.

Features (BD8153EFV)

- 1) Operates in an operating voltage range as low as 2.1 V to 6.0 V.
- 2) Incorporates a step-up DC/DC converter.
- 3) Incorporates a 3.3-V regulator.
- 4) Incorporates positive and negative-side charge pumps.
- 5) Switching frequency of 1100 kHz
- 6) DC/DC converter feedback voltage of 1.24 V \pm 1%
- 7) Incorporates a gate shading function
- 8) Under-voltage lockout protection circuit
- 9) Thermal shutdown circuit
- 10) Overcurrent protection circuit
- 11) HTSSOP-B24 package

Applications

Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limit	Unit
Power supply voltage	VCC	7	V
Vo1 voltage	Vo1	19	V
Vo2 voltage	Vo2	32	V
SW voltage	Vsw	19	V
Maximum junction temperature	Tjmax	150	°C
Power dissipation	Pd	1100*	mW
Operating temperature range	Topr	-40 to 125	°C
Storage temperature range	Tstg	-55 to 150	°C

* Reduced by 4.7 mW/°C over 25°C, when mounted on a glass epoxy board. (70 mm \times 70 mm \times 1.6 mm).

 $(70 \text{ mm} \times 70 \text{ mm} \times 1.6 \text{ mm}).$

Recommended Operating Ranges

Parameter	Symbol	Limit		Unit	
Parameter	Symbol	MIN	MAX	Unit	
Power supply voltage	VCC	2.1	6	V	
Vo1 voltage	Vo1	8	18	V	
SW voltage	Vsw	_	18	V	
SW Current	lsw		1.8	А	
Vo2 voltage	Vo2	—	30	V	

Liquid crystal TV, PC monitor, and TFT-LCD panel

●Electrical Characteristics (Unless otherwise specified, VCC = 5 V; Vo1 = 15 V; Vo2 = 25 V; Ta = 25°C) 1 DC/DC Converter Block

Developmenter	Querra haved		Limit		11-14	
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
[Soft start]				1		
Source current	lso	6	10	14	μA	Vss = 0.5 V
Sinking current	lsi	0.1	0.2	1.0	mA	Vss = 0.5 V,VDD = 1.65 V
[Error amp]						
Input bias current 1	IFB1	_	0.1	0.5	μA	
Feedback voltage 1	VFB1	1.227	1.240	1.253	V	Buffer
Voltage gain	AV	_	200	_	V/V	*
Sinking current	lol	25	50	100	μA	VFB = 1.5 V VCOMP = 0.5 V
Source current	loo	-100	-50	-25	μA	VFB = 1.0 V VCOMP = 0.5 V
[SW]						
ON resistance N-channel	Ron_n	50	200	600	mΩ	*
Leak current N-channel	ILEAKN			10	μA	Vsw = 18 V
Maximum duty cycle	Dмах	75	85	95	%	
[Overcurrent protection]						·
Saw current limit	Insw	2	3	_	А	*

2. Regulator controller

Deveneter	Currents et		Limit		1.1		
Parameter	Symbol	Min.	Min. Typ. Max.		Unit	Conditions	
[Error amp]							
VDD voltage	VDD	3.2	3.3	3.4	V		
Maximum base current	Івмах	4	7	11	mA		
Line regulation	Regl	_	10	30	mV	VCC = 4.5 V to 5.5 V	
Load regulation	RegL	_	10	50	mV	Io = 10 mA to 100 mA	
[Under-voltage lockout prote	ection]						
Off threshold voltage	VROFF	1.7	1.8	1.9	V		
On threshold voltage	Vron	1.6	1.7	1.8	V		

OThis product is not designed for protection against radio active rays. * Design guarantee (No total shipment inspection is made.)

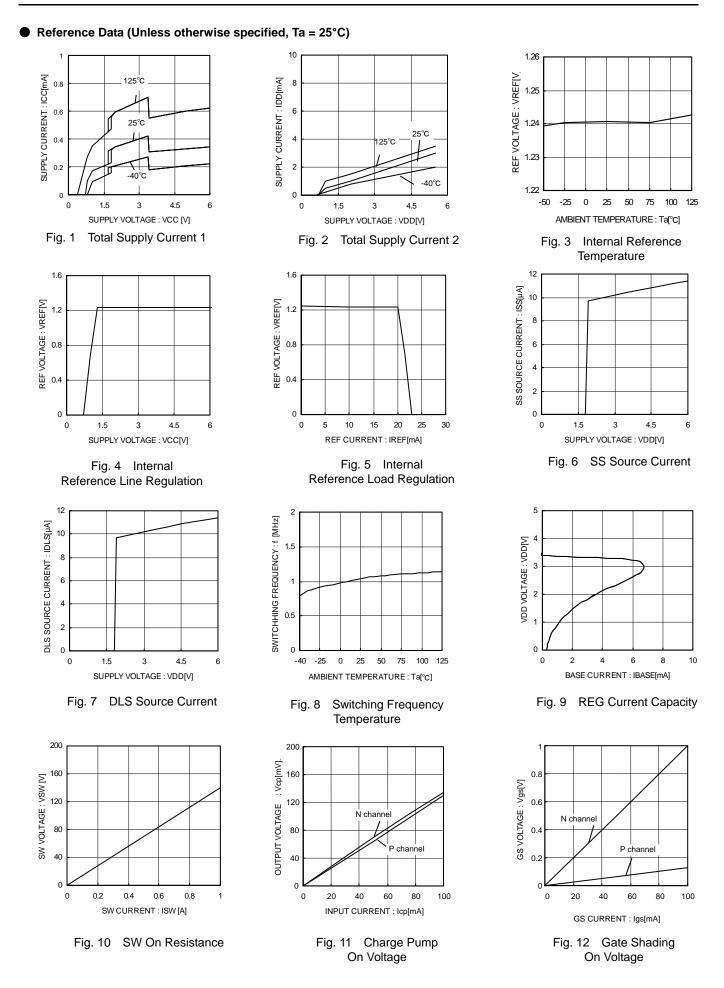
Electrical Characteristics (Unless otherwise specified, VCC = 5 V; Vo1 = 15 V; Vo2 = 25 V; Ta = 25°C) 3.Charge pump

3.Charge pump		_ Limit					
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
[Error amp]		11	*	4 4			
Input bias current 2	IFB2	_	0.1	0.5	μA		
Input bias current 3	IFB3		0.1	0.5	μA		
Feedback voltage 2	VFB2	1.183	1.240	1.307	V		
Feedback voltage 3	VFB3	0.15	0.2	0.25	V		
[Delay start block]							
Source current	Idso	3	5	7	μA	VDLS = 0.5V	
Sinking current	IDSI	0.1	0.5	1.0	mA	VDLS = 0.5V	
Startup voltage	Vst	0.45	0.60	0.75	V		
[Switch]							
ON resistance N-channel	Ron_nc	0.5	2	4	Ω	lo = 10 mA *	
ON resistance P-channel	RON_PC	0.5	4	8	Ω	lo = -10 mA *	
[Diode]							
Voltage of diode	Vf	600	710	800	mV	lo = 10 mA	
[Gate shading block]							
ON resistance N-channel	Ron_ngs	2	10	20	Ω	lo = 10 mA *	
ON resistance P-channel	RON_PGS	2	10	20	Ω	lo = -10 mA *	
Leak current N-channel	ILEAK_NGS	_	_	10	μA		
Leak current P-channel	ILEAK_PGS	—		10	μA		
High voltage	IGH	VDD × 0.7	VDD	_	V		
Low voltage	IGL	—	0	VDD × 0.3	V		
nput current	IIG	8	16.5	30	μA	IG = 3.3 V	

4.Overall

Parameter	Symbol	Limit		Unit	Conditions		
Falametei	Symbol	Min.	Тур.	Max.	Unit	Conditions	
[Reference block]							
Reference voltage	VREF	1.215	1.240	1.265	V		
Drive current	IREF	—	23	—	mA	VREF = 0 V	
Load regulation	ΔV	_	1	10	mV	IREF = -1 mA	
[Oscillator]							
Oscillating frequency	Fosc	0.94	1.1	1.265	MHz		
[Oscillator]							
DET 1 On threshold voltage	VDON1	1.7	1.8	1.9	V		
DET 1 Off threshold voltage	VDOFF1	1.6	1.7	1.8	V		
DET 2 On threshold voltage	VDON2	1.02	1.12	1.22	V		
DET 2 Off threshold voltage	VDOFF2	0.90	1.00	1.10	V		
DET 3 On threshold voltage	Vdon3	0.25	0.30	0.35	V		
DET 3 Off threshold voltage	Vdoff3	0.35	0.41	0.47	V		
DET 4 On threshold voltage	VDON4	1.02	1.12	1.22	V		
DET 4 Off threshold voltage	VDOFF4	0.90	1.00	1.10	V		
[Device]							
Average circuit current	lcc	0.5	2	5	mA	No switching	

OThis product is not designed for protection against radio active rays. * Design guarantee (No total shipment inspection is made.)



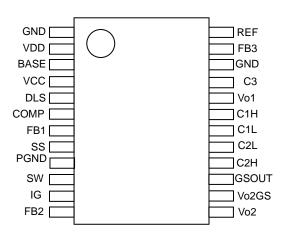
www.rohm.com © 2009 ROHM Co., Ltd. All rights reserved.

6

12.5 15 12.4 OUTPUT VOLTAGE: VDD [V] OUTPUT VOLTAGE : VDD[V] 12.3 Vol VOLTAGE : VO1[V] 12.2 10 12.1 3 12.0 11.9 2 5 11.8 11.7 11.6 11.5 0 0 5 04 08 1.2 16 2 3 4 1.5 3 4.5 0 2 0 6 OUTPUT CURRENT : IDD[mA] SUPPLY VOLTAGE : VCC[V] SUPPLY VOLTAGE : VCC [V] Fig. 14 VDD Load Regulation Fig. 13 Vo1 Line Regulation Fig. 15 Vo1 Line Regulation 100 14 100 . 13V OUTPUT VOLTAGE : VO1[V] 90 13 95 EFFICIENCY [%] EFFICIENCY [%] 12V 80 12 90 1 10.8V 12V 13V 10.8V 70 11 85 60 10 80 300 400 3.5 5.5 100 200 500 600 150 3 4 4.5 5 700 300 450 600 2.5 6 0 0 OUTPUT CURRENT : IO[mA] OUTPUT CURRENT : IO1[mA] SUPPLY VOLTAGE : VCC[V] Fig. 16 Vo1 Load Regulation Fig. 17 Efficiency vs Output Current Fig. 18 Efficiency vs Power Supply Voltage 1600 23.8 24 MAXIMUM CURRENT : IoMAX[mA] OUTPUT VOLTAGE : VO2[V] OUTPUT VOLTAGE : VO2[V] 23.8 23.7 1200 23.6 23.6 800 23.4 400 23.5 23.2 23.4 23 0 1.5 3 4.5 6 10 11.5 13 14.5 16 0 50 100 150 INPUT VOLTAGE : Vo1[v] SUPPLY VOLTAGE : VCC[V] OUTPUT CURRENT : IO2[mA] Fig. 21 Vo2 Load Regulation Fig. 19 Power Supply Voltage vs Fig. 20 Vo2 Line Regulation Max. Output Current Capacity -6 -6 OUTPUT VOLTAGE : VO3[V] OUTPUT VOLTAGE : VO1[V] -6.1 -6.1 IG -6.2 -6.2 VO2GS -6.3 -6.3 -6.4 -6. Ch2 10.0 V A Ch1 / 3.96 12 13 14 15 10 11 0 50 100 150 200 INPUT VOLTAGE : VO1[V] OUTPUT CURRENT : IO[mA] Fig. 22 Negative-side Charge Fig. 23 Negative-side Charge Fig. 24 Gate Shading **Pump Line Regulation** Pump Load Regulation Output Waveform

Reference Data (Unless otherwise specified, Ta = 25°C)

Pin Assignments Diagram



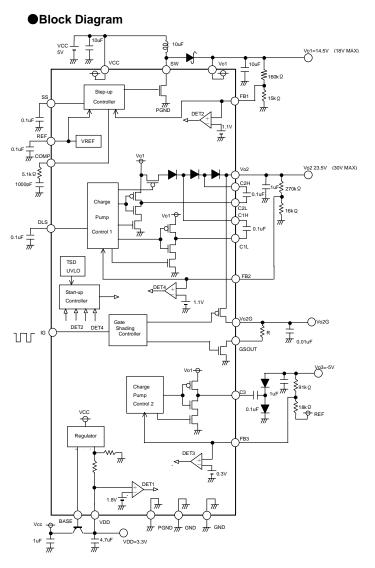


Fig. 25 Pin Arrangements and Block Diagram

Pin Assignments and Function

PIN NO.	Pin name	Function	PIN NO.	Pin name	Function
1	GND	Ground pin	13	Vo2	Positive-side charge pump output
2	VDD	LDO feedback input pin	14	Vo2GS	Gate shading source output pin
3	BASE	LDO base drive output pin	15	GSOUT	Gate shading sink output pin
4	VCC	Power supply input pin	16	C2H	Flying capacitor connection pin
5	DLS	Capacity connection pin for delay start	17	C2L	Flying capacitor connection pin
6	COMP	DC/DC difference amplifier output	18	C1L	Flying capacitor connection pin
7	FB1	DC/DC feedback input	19	C1H	Flying capacitor connection pin
8	SS	Soft start capacitor connection pin	20	Vo1	Negative-side charge pump power supply input pin
9	PGND	Ground pin	21	C3	Negative-side charge pump driver output
10	SW	Switch output	22	GND	Ground pin
11	IG	Gate shading input	23	FB3	Negative-side charge pump feedback input
12	FB2	Positive-side charge pump feedback input	24	REF	Internal standard output pin

Block Function

- Step-up Controller
 - A controller circuit for DC/DC boosting.
 - The switching duty is controlled so that the feedback voltage FB1 is set to 1.24 V (typ.).
 - A soft start operates at the time of starting. Therefore, the switching duty is controlled by the SS pin voltage.
- Charge Pump Control 1

A controller circuit for the positive-side charge pump.

The switching amplitude is controlled so that the feedback voltage FB2 will be set to 1.24 V (typ.).

The start delay time can be set in the DLS terminal at the time of starting.

When the DLS voltage reaches 0.6 V (Typ.), switching waves will be output from the C1L and C2L pins. • Charge Pump Control 2

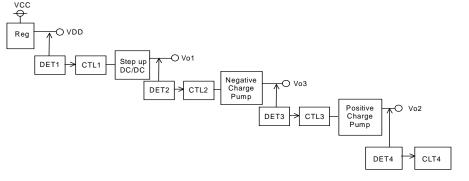
- A controller circuit for the negative-side charge pump.
- The switching amplitude is controlled so that the feedback voltage FB2 will be set to 0.6 V (Typ.).
- Gate Shading Controller
 - A controller circuit of gate shading.
 - The Vo2GS and GSOUT are in on/off control according to IG pin input.
- Regulator Control
 - A regulator controller circuit for VDD voltage generation.
 - The base pin current is controlled so that VDD voltage will be set to 3.3 V (typ.).
- DET 1 to DET 4
- A detection circuit of each output voltage. This detected signal is used for the starting sequential circuit. • Start-up Controller
 - A control circuit for the starting sequence.
 - Controls to start in order of Vcc \rightarrow VDD \rightarrow Vo1 \rightarrow Vo3 \rightarrow Vo2.
- VREF
 - A block that generates internal reference voltage. 1.24V (Typ.) is output.
- TSD/UVLO
 - Thermal shutdown/Under-voltage lockout protection/circuit blocks.

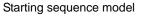
The thermal shutdown circuit is shut down at an IC internal temperature of 175°C and reset at 160°C.

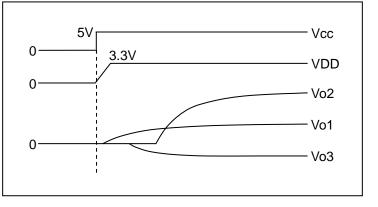
The under-voltage lockout protection circuit shuts down the IC when the VCC is 1.8 V (typ.) or below.

Starting sequence

For malfunction prevention, starting logic control operates so that each output will rise in order of Vcc \rightarrow VDD \rightarrow Vo1 \rightarrow Vo3 \rightarrow Vo2. As shown below, detectors DET1 to DET3 detect that the output on the detection side has reached 90% (typ.) of the set voltage, and starts the next block.







Selecting Application Components

(1) Setting the Output L Constant

The coil to use for output is decided by the rating current ILR and input current maximum value INMAX of the coil.

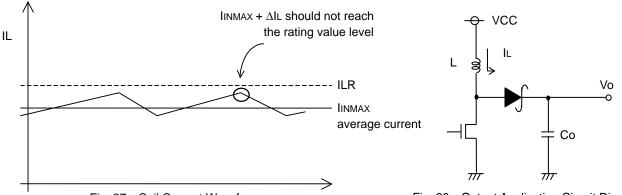




Fig. 28 Output Application Circuit Diagram

Adjust so that INMAX + Δ IL does not reach the rating current value ILR. At this time, Δ IL can be obtained by the following equation. Δ IL = $\frac{1}{L}$ VCC × $\frac{Vo-VCC}{VCC}$ × $\frac{1}{f}$ [A] Here, f is the switching frequency.

 $\Delta IL = L$ VCC × f [A] Here, f is the switching frequency. Set with sufficient margin because the coil value may have the dispersion of ±30%. If the coil current exceeds the rating current ILR of the coil, it may damage the IC internal element.

BD8153EFV uses the current mode DC/DC converter control and has the optimized design at the coil value. A coil inductance (L) of 4.7 µH to 15 µH is recommended from viewpoints of electric power efficiency, response, and stability.

(2) Output Capacity Settings

For the capacitor to use for the output, select the capacitor which has the larger value in the ripple voltage VPP allowance value and the drop voltage allowance value at the time of sudden load change. Output ripple voltage is decided by the following equation.

 $\Delta V_{PP} = I_{LMAX} \times R_{ESR} + \frac{1}{fCo} \times \frac{VCC}{Vo} \times (I_{LMAX} - \frac{\Delta I_{L}}{2})$ [V] Here, f is the switching frequency.

Perform setting so that the voltage is within the allowable ripple voltage range.

For the drop voltage during sudden load change; VDR, please perform the rough calculation by the following equation. $VDR = \frac{\Delta I}{Co} \times 10 \text{ us}$ [V]

However, 10 µs is the rough calculation value of the DC/DC response speed. Please set the capacitance considering the sufficient margin so that these two values are within the standard value range.

(3) Selecting the Input Capacitor

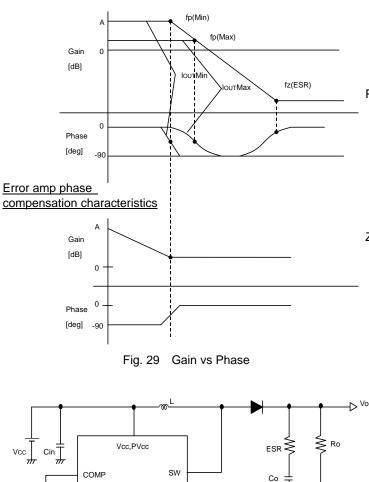
Since the peak current flows between the input and output at the DC/DC converter, a capacitor is required to install at the input side. For the reason, the low ESR capacitor is recommended as an input capacitor which has the value more than 10 μ F and less than 100 m Ω . If a capacitor out of this range is selected, the excessive ripple voltage is superposed on the input voltage, accordingly it may cause the malfunction of IC.

However these conditions may vary according to the load current, input voltage, output voltage, inductance and switching frequency. Be sure to perform the margin check using the actual product.

(4) Setting Rc, Cc of the Phase Compensation Circuit

In the current mode control, since the coil current is controlled, a pole (phase lag) made by the CR filter composed of the output capacitor and load resistor will be created in the low frequency range, and a zero (phase lead) by the output capacitor and ESR of capacitor will be created in the high frequency range. In this case, to cancel the pole of the power amplifier, it is easy to compensate by adding the zero point with Cc and Rc to the output from the error amp as shown in the illustration.

Open loop gain characteristics



$$Fp = \frac{1}{2 \pi \times Ro \times Co} [Hz]$$
$$fz(ESR) = \frac{1}{2 \pi \times ESR \times CO} [Hz]$$

Pole at the power amplification stage

When the output current reduces, the load resistance R_0 increases and the pole frequency lowers.

$$fp(Min) = \frac{1}{2 \pi \times ROMax \times CO} [Hz] \leftarrow at light load$$
$$fz(Max) = \frac{1}{2 \pi \times ROMin \times CO} [Hz] \leftarrow at heavy load$$

Zero at the power amplification stage

When the output capacitor is set larger, the pole frequency lowers but the zero frequency will not change. (This is because the capacitor ESR becomes 1/2 when the capacitor becomes 2 times.)

$$fp(Amp.) = \frac{1}{2 \pi \times Rc \times Cc} [Hz]$$



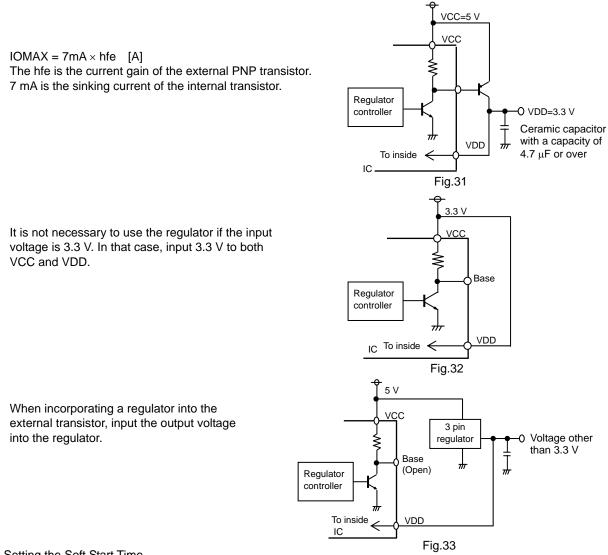
GND.PGND

It is possible to realize the stable feedback loop by canceling the pole fp(Min.), which is created by the output capacitor and load resistor, with CR zero compensation of the error amp as shown below.

BD8153EFV

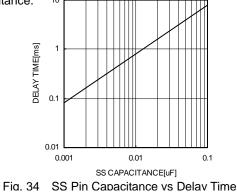
(5) Regulator Controller Settings

The IC incorporates a 3.3-V regulator controller, and a regulator can be formed by using an external PNP transistor. Design the current capability of the regulator with a margin according to the following formula.



(6) Setting the Soft Start Time

Soft start is required to prevent the coil current at the time of start from increasing and the overshoot of the output voltage at the starting time. The relation between the capacity and soft start time is shown in the following figure. Refer to the figure and set capacity C1.Soft start is required to prevent the coil current at the time of start from increasing and the overshoot of the output voltage at the starting time. Fig. 34 shows the relation between the capacitance and soft start time. Please refer to it to set the capacitance.

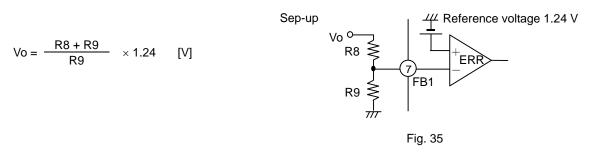


As the capacitance, 0.001μ F to 0.1μ F is recommended. If the capacitance is set lower than 0.001μ F, the overshooting may occur on the output voltage. If the capacitance is set larger than 0.1μ F, the excessive back current flow may occur in the internal parasitic elements when the power is turned OFF and it may damage IC. When there is the activation relation (sequences) with other power supplies, be sure to use the high accuracy product (such as X5R). Soft start time may vary according to the input voltage, loads, coils and output capacity. Be sure to verify the operation using the actual product.

www.rohm.com © 2009 ROHM Co., Ltd. All rights reserved.

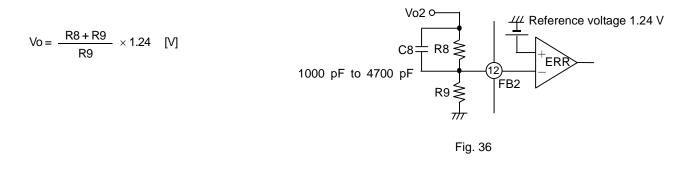
(7) Design of the Feedback Resistor Constant

Refer to the following equation to set the feedback resistor. As the setting range, 10 k Ω to 330 k Ω is recommended. If the resistor is set lower than a 10 k Ω , it causes the reduction of power efficiency. If it is set more than 330 k Ω , the offset voltage becomes larger by the input bias current 0.4 μ A(Typ.) in the internal error amplifier.



(8) Positive-side Charge Pump Settings

BU8513EFV incorporates a charge pump controller, thus making it possible to generate stable gate voltage. The output voltage is determined by the following formula. As the setting range, $10 \text{ k}\Omega$ to $330 \text{ k}\Omega$ is recommended. If the resistor is set lower than a $10\text{k}\Omega$, it causes the reduction of power efficiency. If it is set more than $330 \text{ k}\Omega$, the offset voltage becomes larger by the input bias current 0.4 μ A (Typ.) in the internal error amp.



In order to prevent output voltage overshooting, add capacitor C8 in parallel with R8. The recommended capacitance is 1000 pF to 4700 pF. If a capacitor outside this range is inserted, the output voltage may oscillate. By connecting capacitance to the DLS, a rising delay time can be set for the positive-side charge pump.

The delay time is determined by the following formula.

• Delay time of charge pump block t DELAY

t DELAY = (CDLS \times 0.6)/5 µA [s6]

where, CDLS is the external capacitance.

(9) Negative-side Charge Pump Settings

BU8513EFV incorporates a charge pump controller for negative voltage, thus making it possible to generate stable gate voltage. The output voltage is determined by the following formula. As the setting range, $10 \text{ k}\Omega$ to $330 \text{ k}\Omega$ is recommended. If the resistor is set lower than a $10 \text{ k}\Omega$, it causes the reduction of power efficiency. If it is set more than $330 \text{ k}\Omega$, the offset voltage becomes larger by the input bias current 0.4 μ A (Typ.) in the internal error amp.

$$Vo3 = -\frac{R6}{R7} \times 1.04 + 0.2 V \quad [V]$$

$$1000 \text{ pF to 4700 pF}$$

$$R7 = -\frac{R6}{R7} \times 1.04 + 0.2 V \quad [V]$$

The delay time is internally fixed at 200 us.

In order to prevent output voltage overshooting, insert capacitor C6 in parallel with R6. The recommended capacitance is 1000 pF to 4700 pF. If a capacitor outside this range is inserted, the output voltage may oscillate.

www.rohm.com © 2009 ROHM Co., Ltd. All rights reserved. Fig.37

•Gate Shading Setting Method

The IG input signal allows the high-level and low-level control of the positive-side gate voltage. The slope of output can be set by the external RC. The recommended resistance set value is 200Ω to $5.1 \text{ k}\Omega$ and the recommended capacitor set value is $0.001 \text{ }\mu\text{F}$ to $0.1 \text{ }\mu\text{F}$. The aggravation of efficiency may be caused if settings outside this range are made. Determine ΔV by referring to the following value. The following calculation formula is used for ΔV .

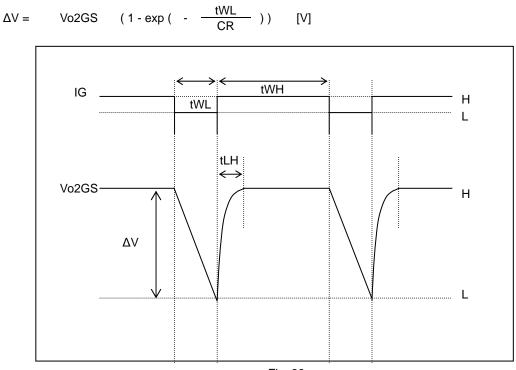
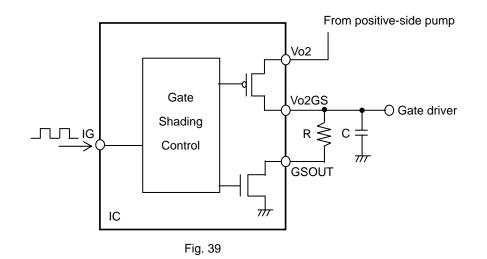


Fig. 38

PARAMETER	CVMDOI	SYMBOL LIMIT UNI				CONDITION	
PARAMETER	STINIBUL			UNIT	CONDITION		
IG "L" Time	tWL	1	2	-	μs	-	
IG "H" Time	tWH	1	18	•	μs	-	
Vo2GS "H" to "L Voltage difference	ΔV	-	10	-	V	TWL = 2 μ s ,R = 500 Ω *	
Vo2GS "L" to "H" Time	tLH	-	0.1	-	μs	$\Delta V = 10 V *$	

TIMING STANDARD VALUE

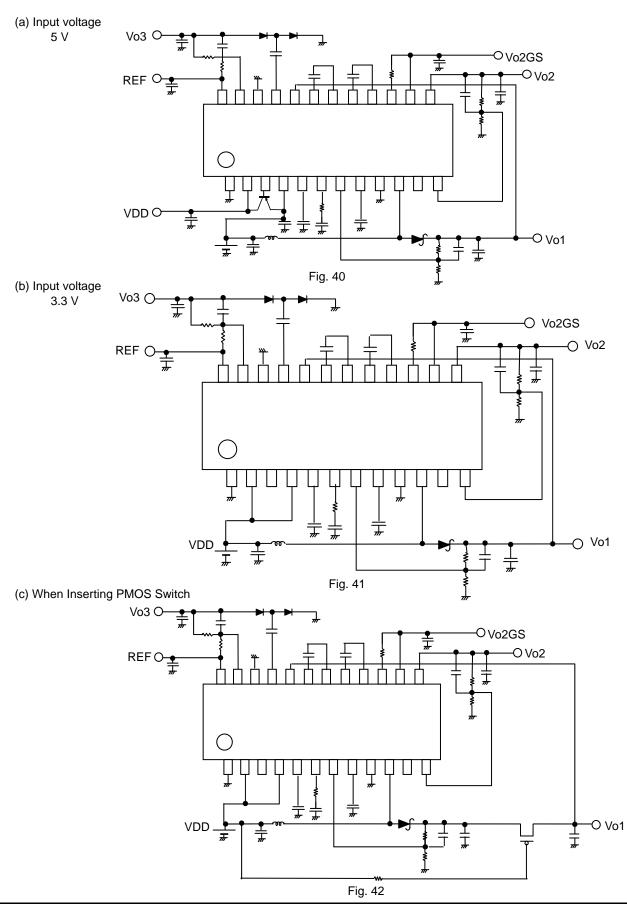


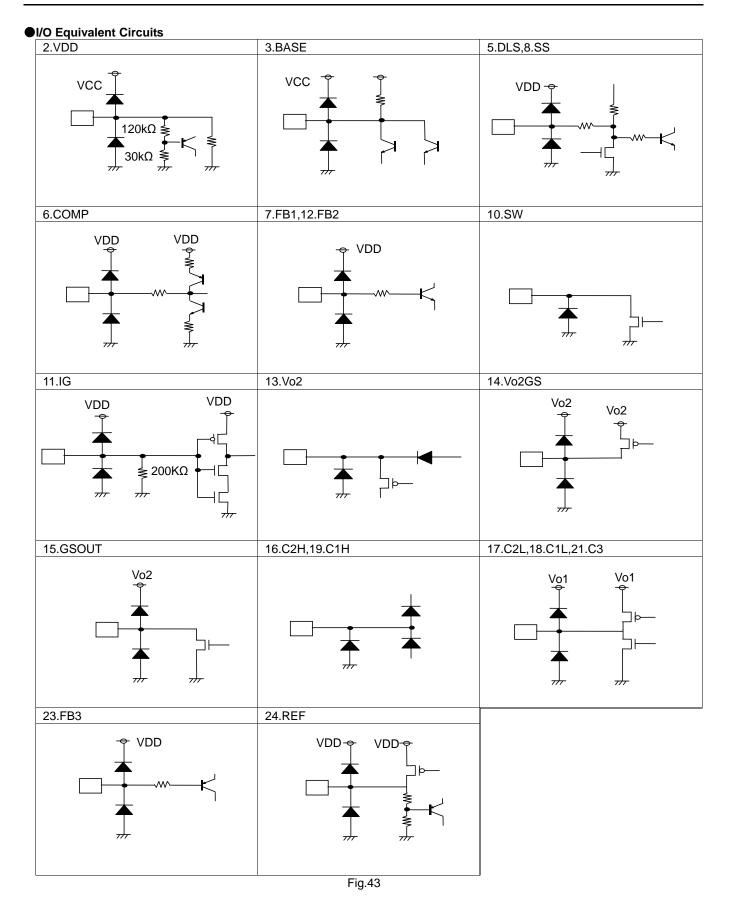
Application Examples

BD8153EFV

*Although we are confident that the application circuit diagram reflects the best possible recommendations, be sure to verify circuit characteristics for your particular application.

When a circuit is used modifying the externally connected circuit constant, be sure to decide allowing sufficient margins considering the dispersion of values by external parts as well as our IC including not only the static but also the transient characteristic. For the patent, we have not acquired the sufficient confirmation. Please acknowledge the status.





Operation Notes

1) Absolute maximum ratings

Use of the IC in excess of absolute maximum ratings such as the applied voltage or operating temperature range may result in IC damage. Assumptions should not be made regarding the state of the IC (short mode or open mode) when such damage is suffered. A physical safety measure such as a fuse should be implemented when use of the IC in a special mode where the absolute maximum ratings may be exceeded is anticipated.

2) GND potential

Ensure a minimum GND pin potential in all operating conditions.

3) Setting of heat

Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions.

4) Pin short and mistake fitting

Use caution when orienting and positioning the IC for mounting on printed circuit boards. Improper mounting may result in damage to the IC. Shorts between output pins or between output pins and the power supply and GND pins caused by the presence of a foreign object may result in damage to the IC.

5) Actions in strong magnetic field

Use caution when using the IC in the presence of a strong magnetic field as doing so may cause the IC to malfunction.

6) Testing on application boards

When testing the IC on an application board, connecting a capacitor to a pin with low impedance subjects the IC to stress. Always discharge capacitors after each process or step. Ground the IC during assembly steps as an antistatic measure, and use similar caution when transporting or storing the IC. Always turn the IC's power supply off before connecting it to or removing it from a jig or fixture during the inspection process.

7) Ground wiring patterns

When using both small signal and large current GND patterns, it is recommended to isolate the two ground patterns, placing a single ground point at the application's reference point so that the pattern wiring resistance and voltage variations caused by large currents do not cause variations in the small signal ground voltage. Be careful not to change the GND wiring patterns of any external components.

8) This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P/N junctions are formed at the intersection of these P layers with the N layers of other elements to create a variety of parasitic elements.

For example, when the resistors and transistors are connected to the pins as shown in Fig. 44, a parasitic diode or a transistor operates by inversing the pin voltage and GND voltage.

The formation of parasitic elements as a result of the relationships of the potentials of different pins is an inevitable result of the IC's architecture. The operation of parasitic elements can cause interference with circuit operation as well as IC malfunction and damage. For these reasons, it is necessary to use caution so that the IC is not used in a way that will trigger the operation of parasitic elements, such as the application of voltages lower than the GND (P board) voltage to input and output pins.

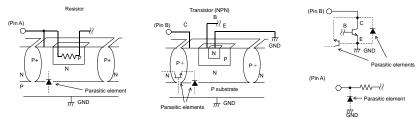


Fig.44 Example of a Simple Monolithic IC Architecture

9) Overcurrent protection circuits

An over current protection circuit designed according to the output current is incorporated for the prevention of IC destruction that may result in the event of load shorting. This protection circuit is effective in preventing damage due to sudden and unexpected accidents. However, the IC should not be used in applications characterized by the continuous operation or transitioning of the protection circuits. At the time of thermal designing, keep in mind that the current capability has negative characteristics to temperatures.

10) Thermal shutdown circuit

This IC incorporates a built-in thermal shutdown circuit for the protection from thermal destruction. The IC should be used within the specified power dissipation range. However, in the event that the IC continues to be operated in excess of its power dissipation limits, the attendant rise in the chip's temperature Tj will trigger the thermal shutdown circuit to turn off all output power elements. The circuit automatically resets once the chip's temperature Tj drops. Operation of the thermal shutdown circuit presumes that the IC's absolute maximum ratings have been exceeded. Application designs should never make use of the thermal shutdown circuit.

11) Testing on application boards

At the time of inspection of the installation boards, when the capacitor is connected to the pin with low impedance, be sure to discharge electricity per process because it may load stresses to the IC. Always turn the IC's power supply off before connecting it to or removing it from a jig or fixture during the inspection process. Ground the IC during assembly steps as an antistatic measure, and use similar caution when transporting or storing the IC.

Power Dissipation Reduction

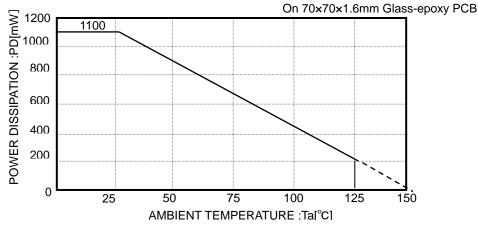
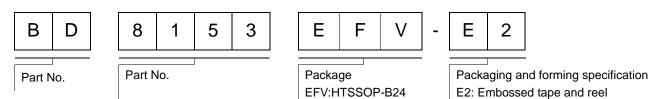
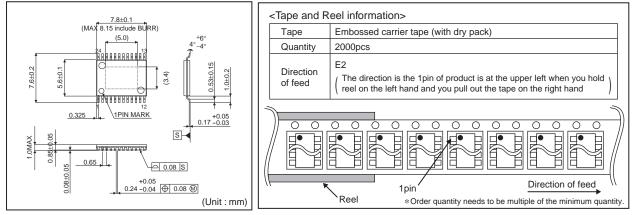


Fig.45

Ordering part number



HTSSOP-B24



Notice

Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment ^(Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

JAPAN	USA	EU	CHINA
CLASSⅢ		CLASS II b	
CLASSⅣ	CLASSⅢ	CLASSⅢ	CLASSII

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
 - [a] Installation of protection circuits or other protective devices to improve system safety
 - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
 - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [C] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

QR code printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since our Products might fall under controlled goods prescribed by the applicable foreign exchange and foreign trade act, please consult with ROHM representative in case of export.

Precaution Regarding Intellectual Property Rights

- 1. All information and data including but not limited to application example contained in this document is for reference only. ROHM does not warrant that foregoing information or data will not infringe any intellectual property rights or any other rights of any third party regarding such information or data. ROHM shall not be in any way responsible or liable for infringement of any intellectual property rights or other damages arising from use of such information or data.:
- 2. No license, expressly or implied, is granted hereby under any intellectual property rights or other rights of ROHM or any third parties with respect to the information contained in this document.

Other Precaution

- 1. This document may not be reprinted or reproduced, in whole or in part, without prior written consent of ROHM.
- 2. The Products may not be disassembled, converted, modified, reproduced or otherwise changed without prior written consent of ROHM.
- 3. In no event shall you use in any way whatsoever the Products and the related technical information contained in the Products or this document for any military purposes, including but not limited to, the development of mass-destruction weapons.
- 4. The proper names of companies or products described in this document are trademarks or registered trademarks of ROHM, its affiliated companies or third parties.

General Precaution

- 1. Before you use our Products, you are requested to care fully read this document and fully understand its contents. ROHM shall not be in an y way responsible or liable for failure, malfunction or accident arising from the use of a ny ROHM's Products against warning, caution or note contained in this document.
- 2. All information contained in this docume nt is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sale s representative.
- 3. The information contained in this document is provided on an "as is" basis and ROHM does not warrant that all information contained in this document is accurate an d/or error-free. ROHM shall not be in an y way responsible or liable for any damages, expenses or losses incurred by you or third parties resulting from inaccuracy or errors of or concerning such information.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ROHM Semiconductor: BD8153EFV-E2



ООО "ЛайфЭлектроникс"

ИНН 7805602321 КПП 780501001 Р/С 40702810122510004610 ФАКБ "АБСОЛЮТ БАНК" (ЗАО) в г.Санкт-Петербурге К/С 3010181090000000703 БИК 044030703

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный) Email: org@lifeelectronics.ru

www.lifeelectronics.ru